



# **DMMT5401**

## MATCHED PNP SMALL SIGNAL SURFACE MOUNT **TRANSISTOR**

#### **Features**

Epitaxial Planar Die Construction

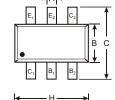
Complementary NPN Type Available (DMMT5551) Ideal for Low Power Amplification and Switching

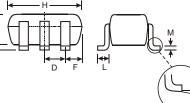
Intrinsically Matched PNP Pair (Note 1)

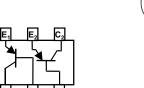
2% Matched Tolerance, hFE, VCE(SAT), VBE(SAT)

Lead Free/RoHS Compliant (Note 4)

"Green" Device, Note 5 and 6







SOT-26										
Dim	Min	Max	Тур							
Α	0.35	0.50	0.38							
В	1.50	1.70	1.60							
С	2.70	3.00	2.80							
D			0.95							
F			0.55							
Н	2.90	3.10	3.00							
J	0.013	0.10	0.05							
K	1.00	1.30	1.10							
L	0.35	0.55	0.40							
M	0.10	0.20	0.15							
	0	8								
All Dimensions in mm										

## **Mechanical Data**

Case: SOT-26

Case Material: Molded Plastic, "Green" Molding Compound, Note 7. UL Flammability Classification

Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C

Terminal Connections: See Diagram

Terminals: Solderable per MIL-STD-202, Method 208

Lead Free Plating (Matte Tin Finish annealed over

Copper leadframe).

Marking (See Page 2): K4S

Order & Date Code Information: See Page 2

Weight: 0.006 grams (approximate)

#### **Maximum Ratings** @ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V <sub>CBO</sub>	-160	V	
Collector-Emitter Voltage	V <sub>CEO</sub>	-150	V	
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V	
Collector Current - Continuous (Note 2)	I <sub>C</sub>	-200	mA	
Power Dissipation (Note 2, 3)	Pd	300	mW	
Thermal Resistance, Junction to Ambient (Note 2)	R <sub>JA</sub>	417	°C/W	
Operating and Storage and Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	С	

- Notes: 1. Built with adjacent die from a single wafer.
  - 2. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
  - 3. Maximum combined dissipation.
  - 4. No purposefully added lead.
  - 5. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
  - 6. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



## Electrical Characteristics @ TA = 25 C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition					
OFF CHARACTERISTICS (Note 7)										
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-160		V	I <sub>C</sub> = -100 A, I <sub>E</sub> = 0					
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-150		V	$I_C = -1.0 \text{mA}, I_B = 0$					
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5.0		V	I <sub>E</sub> = -10 A, I <sub>C</sub> = 0					
Collector Cutoff Current	I <sub>CBO</sub>		-50	nA A	$V_{CB} = -120V, I_E = 0$ $V_{CB} = -120V, I_E = 0, T_A = 100 C$					
Emitter Cutoff Current	I <sub>EBO</sub>		-50	nA	$V_{EB} = -3.0V, I_{C} = 0$					
ON CHARACTERISTICS (Note 7)										
DC Current Gain (Note 8)	h <sub>FE</sub>	50 60 50	240		I <sub>C</sub> = -1.0mA, V <sub>CE</sub> = -5.0V I <sub>C</sub> = -10mA, V <sub>CE</sub> = -5.0V I <sub>C</sub> = -50mA, V <sub>CE</sub> = -5.0V					
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		-0.2 -0.5	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA					
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>		-1.0	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA					
SMALL SIGNAL CHARACTERISTICS										
Output Capacitance	C <sub>obo</sub>		6.0	pF	$V_{CB} = -10V$ , $f = 1.0MHz$ , $I_E = 0$					
Small Signal Current Gain	h <sub>fe</sub>	40	200		$V_{CE} = -10V, I_{C} = -1.0mA,$ f = 1.0kHz					
Current Gain-Bandwidth Product	f <sub>T</sub>	100	300	MHz	$V_{CE} = -10V, I_{C} = -10mA,$ f = 100MHz					
Noise Figure	NF		8.0	dB	$V_{CE} = -5.0V$ , $I_{C} = -200$ A, $R_{S} = 10$ f = 1.0kHz					

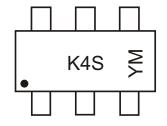
## Ordering Information (Note 6 & 9)

Device	Packaging	Shipping			
DMMT5401-7-F	SOT-26	3000/Tape & Reel			

Notes:

- 6. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. The DC Current Gain, h<sub>FE</sub>, (matched at I<sub>C</sub> = -10mA and V<sub>CE</sub> = -5V) Collector Emitter Saturation Voltage, V<sub>CE(SAT)</sub>, and Base Emitter Saturation Voltage, V<sub>BE(SAT)</sub> are matched with typical matched tolerances of 1% and maximum of 2%.
- $9. \ \ \text{For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.}$

## **Marking Information**



K4S = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006

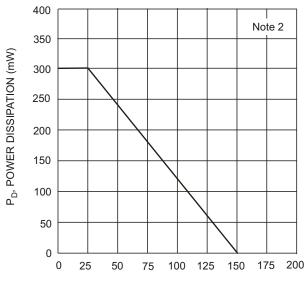
M = Month ex: 9 = September

## Date Code Key

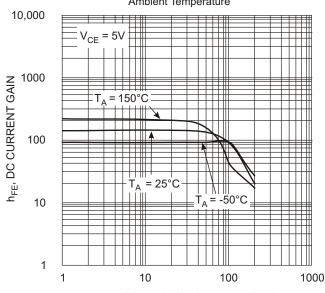
Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

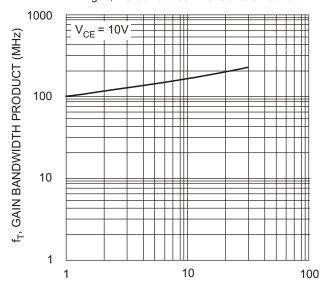




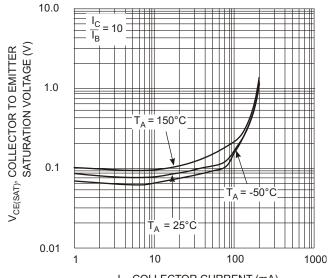
T<sub>A</sub>, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs Ambient Temperature



I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 5, Gain Bandwidth Product vs Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 2, Collector Emitter Saturation Voltage
vs. Collector Current

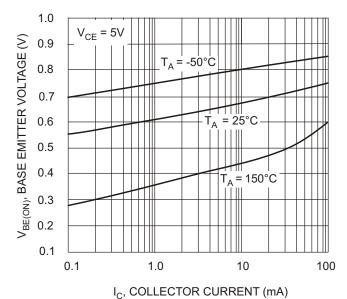


Fig. 4, Base Emitter Voltage vs. Collector Current



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